

Application No.: 10/777,599

Docket No.: JCLA12098

In the Claims

Please amend the claims as follows.

1. (canceled)
2. (canceled)
3. (canceled)

4. (currently amended) A voltage level shifter, comprising:

an AND gate for processing a first control signal and an input signal to produce a synchronizing signal, wherein the first control signal is a periodic signal;

a transistor device having a first transistor and a second transistor, wherein a drain of the first transistor and a drain of the second transistor are electrically connected at a first contact point, a source of the first transistor then is electrically connected to a ground and a source of the second transistor is electrically connected to a voltage source, a gate of the first transistor is electrically connected to the synchronizing signal and a gate of the second transistor is electrically connected to a second control signal having the same phase as the first control signal ;

~~The voltage level shifter of claim 1 further comprising:~~

a switch, controlled by the first control signal, wherein one terminal of the switch is electrically connected to the first contact point and the other terminal of the switch is electrically connected to a second contact point; the drain of the first transistor;

a buffer for producing an output signal, wherein an input terminal of the buffer is connected to the second contact point; and

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a capacitor, wherein one terminal of the capacitor is electrically connected to the second contact point for storing a signal level of the second contact point, and the other terminal of the capacitor is electrically connected to the ground.

5. (original) The voltage level shifter of claim 4, wherein the switch comprises an n-type metal oxide semiconductor.

6. (canceled)

7. (currently amended) The voltage level shifter of claim ~~4~~, wherein the buffer comprises an inverter having at least a PMOS transistor and a NMOS transistor.

8. (currently amended) The voltage level shifter of claim ~~4~~, wherein the capacitor comprises ~~a parasitic capacitor for a transistor~~ provided as a parasitic capacitor.

9. (canceled)

10. (canceled)

11. (currently amended) The voltage level shifter of claim ~~4~~, wherein the AND gate comprises a low voltage transistor device, and the transistor device, the buffer and the capacitor comprise high voltage transistor devices.

12. (currently amended) The voltage level shifter of claim ~~4~~, wherein the first control signal inputted to the AND gate comprises a low voltage signal, and the second first-control signal inputted to the second transistor is ~~adjusted to~~ comprises a high voltage signal. having a phase the same as a phase of the first control signal inputted to the AND gate.

13. (canceled)

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14. (currently amended) A voltage level shifter, comprising:

a switch device;

an input transistor device comprises:

a first transistor, electrically connected to a voltage source;

a second transistor; and

a third transistor, both electrically connected to a ground;

wherein the first transistor is a PMOS transistor, the second and third transistors are NMOS transistors, a gate of the first transistor and a gate of the second transistor are electrically connected to ~~the~~ a first control signal, a gate of the third transistor is electrically connected to an input signal, ~~a drain of the second transistor is electrically connected to the switch,~~ and a drain of the first transistor and a drain of the second transistors are electrically connected at a first contact point;

wherein the switch is controlled by ~~the~~ a first control signal, in which one terminal of the switch is electrically connected to the first contact point;

a capacitor, electrically connected to the other terminal of the switch at a second contact point for storing a signal level of the second contact point; and

a buffer for producing an output signal, wherein the input terminal of the buffer is electrically connected to the second contact point.

15. (currently amended) The voltage level shifter of claim 14, wherein the capacitor comprises ~~a parasitic capacitor for a transistor~~ provided as parasitic capacitor.

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16. (currently amended) The voltage level shifter of claim 14, said capacitor further comprising:

a fourth transistor;

a fifth transistor; and

a second control signal;

wherein the capacitor is electrically connected to the fourth transistor, in which a drain, a gate and a source of the fourth transistor are electrically connected to the second contact point, an output terminal of the buffer and the fifth transistor respectively, a gate of the fifth transistor is electrically connected to the second control signal, and the fourth and the fifth transistors are PMOS transistors.

17. (currently amended) The voltage level shifter of claim ~~14~~ 16, wherein the first control signal is a periodic negative pulse and the second control signal is a periodic positive pulse, the first and the second control signals are synchronized and a width of the negative pulse is narrower than a width of the positive pulse.

18. (original) The voltage level shifter of claim 16, wherein the first, second, third, fourth and fifth transistors and the buffer comprise high voltage field effect transistor devices.